

BUT12AX

Silicon diffused power transistor

Rev. 01 — 16 June 2004

Product data

1. Product profile

1.1 Description

High voltage, high speed, NPN power transistor in a plastic package.

1.2 Features

- Isolated package
- Fast switching.

1.3 Applications

- Inverters
- Switching regulators
- Motor control systems
- DC-to-DC converters.

1.4 Quick reference data

- $V_{CESM} \leq 1000 \text{ V}$
- $I_C \leq 8 \text{ A}$
- $P_{tot} \leq 23 \text{ W}$
- $t_f \leq 0.8 \text{ } \mu\text{s}$.

2. Pinning information

Table 1: Pinning - SOT186A (TO-220F), simplified outline and symbol

| Pin | Description | Simplified outline | Symbol |
|-----|----------------------------|--------------------|--------|
| 1 | base (b) | | |
| 2 | collector (c) | | |
| 3 | emitter (e) | | |
| mb | mounting base; isolated | | |

SOT186A (TO-220F)



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3. Ordering information

Table 2: Ordering information

| Type number | Package | | Version |
|-------------|---------|--|---------|
| | Name | Description | |
| BUT12AX | TO-220F | Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3 leads. | SOT186A |

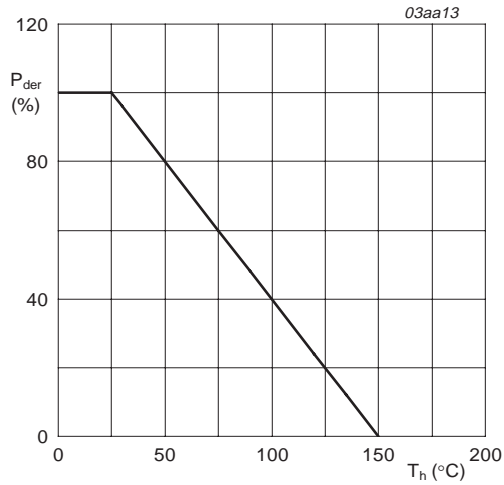
4. Limiting values

Table 3: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

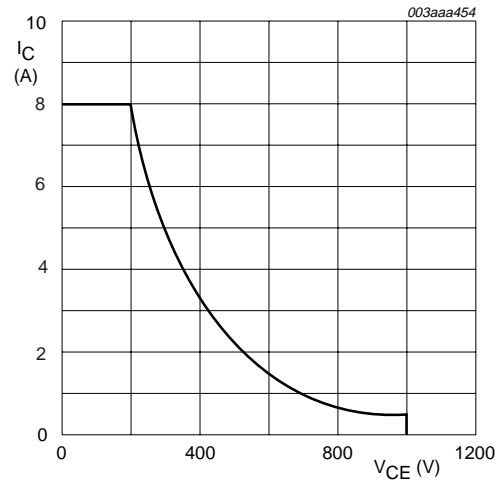
| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------|--------------------------------|---------------------------------|-------|------|------|
| V_{CESM} | peak collector-emitter voltage | $V_{BE} = 0\text{ V}$ | - | 1000 | V |
| V_{CEO} | collector-emitter voltage | base open circuit | - | 450 | V |
| I_C | collector current | Figure 2 and 3 | - | 8 | A |
| I_{Csat} | collector saturation current | | - | 5 | A |
| I_{CM} | peak collector current | Figure 3 | - | 20 | A |
| I_B | base current (DC) | | - | 4 | A |
| I_{BM} | peak base current | | - | 6 | A |
| P_{tot} | total power dissipation | $T_h = 25\text{ °C}$; Figure 1 | [1] - | 23 | W |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| T_j | junction temperature | | - | +150 | °C |

[1] Mounted without heatsink compound.



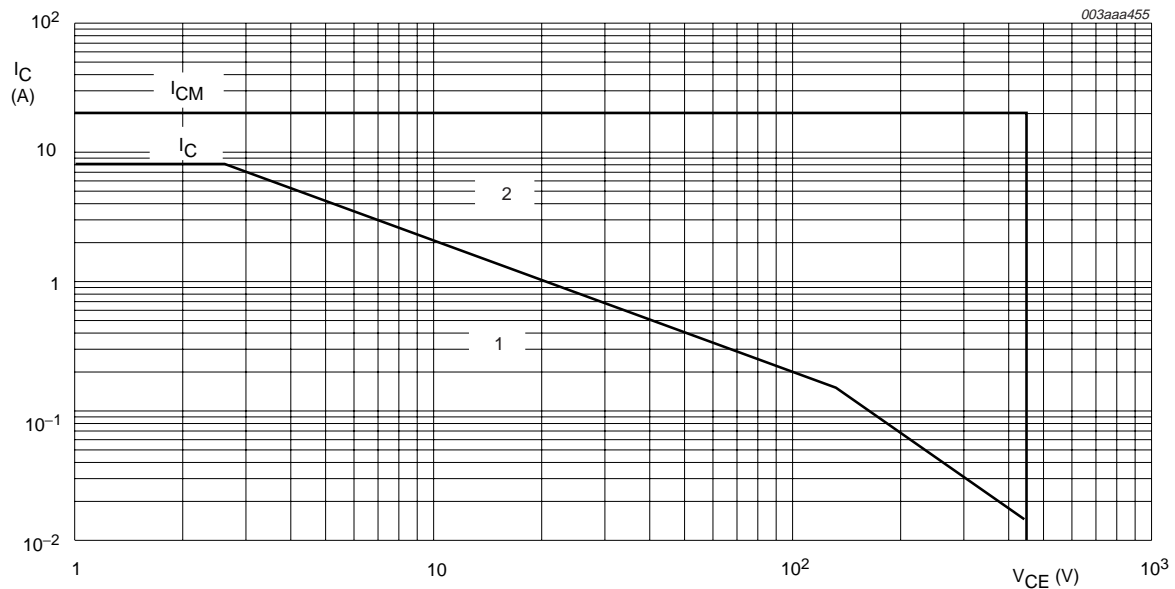
$$P_{der} = \frac{P_{tot}}{P_{tot(25^\circ C)}} \times 100\%$$

Fig 1. Normalized total power dissipation as a function of heatsink temperature.



$V_{BE} = -1 \text{ V to } -5 \text{ V}; T_h = 100^\circ \text{C}.$

Fig 2. Reverse bias safe operating area; continuous collector current as a function of collector-emitter voltage.



$T_h = 25^\circ \text{C}$

- 1 - Region of permissible DC operation.
- 2 - Permissible extension for repetitive operation.

Fig 3. Forward bias safe operating area; continuous and peak collector currents as a function of collector-emitter voltage.

5. Thermal characteristics

Table 4: Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|---------------|--|-----------------------------------|-----|-----|-----|------|-----|
| $R_{th(j-h)}$ | thermal resistance from junction to heatsink | Mounted without heatsink compound | [1] | - | - | 5.5 | K/W |
| | | Mounted with heatsink compound | [1] | - | - | 3.9 | K/W |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | | - | 55 | - | K/W | |

[1] External heatsink connected to mounting base.

6. Characteristics

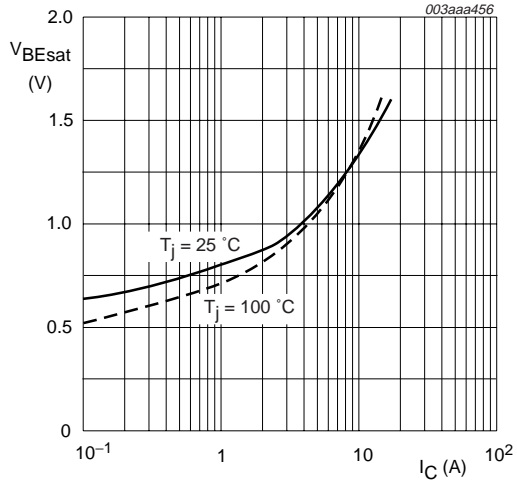
Table 5: Characteristics

$T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|--------------------------------|--------------------------------------|---|-----|-----|-----|---------------|---------------|
| Static characteristics | | | | | | | |
| V_{CE0sus} | collector-emitter sustaining voltage | $I_C = 100\text{ mA}$; $I_{Boff} = 0\text{ A}$; $L = 25\text{ mH}$; Figure 9 and 10 | 400 | - | - | V | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = 5\text{ A}$; $I_B = 1\text{ A}$; Figure 5 | - | - | 1.5 | V | |
| V_{BEsat} | base-emitter saturation voltage | $I_C = 5\text{ A}$; $I_B = 1\text{ A}$; Figure 4 | - | - | 1.5 | V | |
| I_{CES} | collector-emitter cut-off current | $V_{CE} = V_{CESM}$; $V_{BE} = 0\text{ V}$ | | | | | |
| | | $T_j = 25\text{ }^\circ\text{C}$ | [1] | - | - | 1 | mA |
| | | $T_j = 125\text{ }^\circ\text{C}$ | [1] | - | - | 3 | mA |
| h_{FE} | DC current gain | $V_{CE} = 5\text{ V}$; Figure 8 | | | | | |
| | | $I_C = 10\text{ mA}$ | 10 | 18 | 35 | | |
| | | $I_C = 1\text{ A}$ | 10 | 20 | 35 | | |
| Dynamic characteristics | | | | | | | |
| t_{on} | turn-on time | $I_{Con} = 5\text{ A}$; $I_{Bon} = I_{Boff} = 1\text{ A}$; resistive load; Figure 11 and 12 | - | - | 1 | μs | |
| t_s | carrier storage time | $I_{Con} = 5\text{ A}$; $I_{Bon} = I_{Boff} = 1\text{ A}$; resistive load; Figure 11 and 12 | [2] | - | - | 4 | μs |
| | | $I_{Con} = 5\text{ A}$; $I_{Bon} = 1\text{ A}$; $V_{CL} = 250\text{ V}$; $T_{mb} = 100\text{ }^\circ\text{C}$; inductive load; Figure 13 and 14 | - | 1.9 | 2.5 | μs | |
| t_f | fall time | $I_{Con} = 5\text{ A}$; $I_{Bon} = I_{Boff} = 1\text{ A}$; resistive load; Figure 11 and 12 | - | - | 0.8 | μs | |
| | | $I_{Con} = 5\text{ A}$; $I_{Bon} = 1\text{ A}$; $V_{CL} = 300\text{ V}$; $T_{mb} = 100\text{ }^\circ\text{C}$; inductive load; Figure 13 and 14 | - | 200 | 300 | ns | |

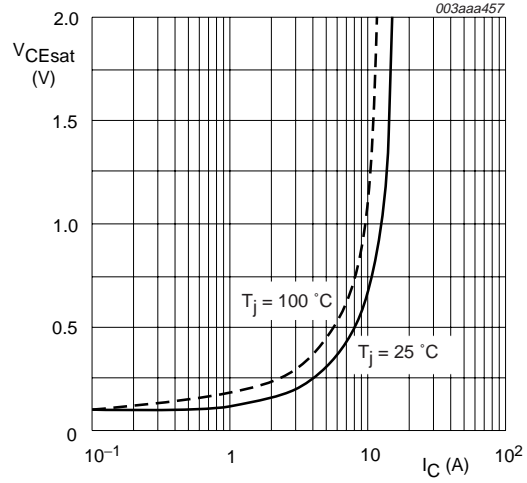
[1] Measured with a half-sinewave voltage.

[2] turn-off storage time



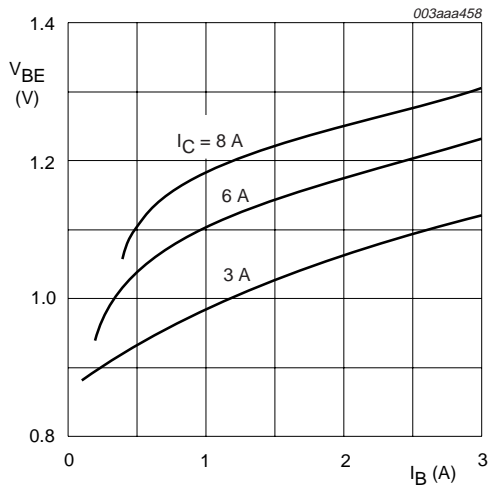
$T_j = 25^\circ\text{C}$ and 100°C

Fig 4. Base-emitter saturation voltage as a function of collector current; typical values.



$T_j = 25^\circ\text{C}$ and 100°C

Fig 5. Collector-emitter saturation voltage as a function of collector current; typical values.



$T_j = 25^\circ\text{C}$

Fig 6. Base-emitter voltage as a function of base current; typical values.

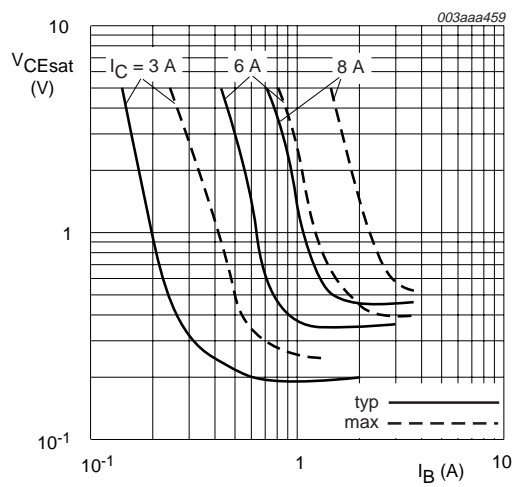
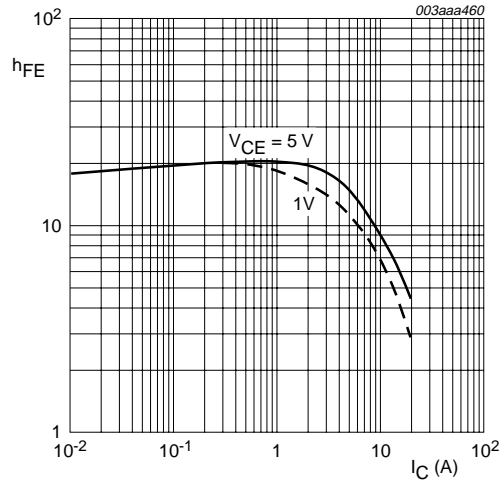


Fig 7. Collector-emitter saturation voltage as a function base current; typical and maximum values.



$V_{CE} = 5\text{ V and }1\text{ V}$

Fig 8. DC current gain as a function of collector current; typical values.

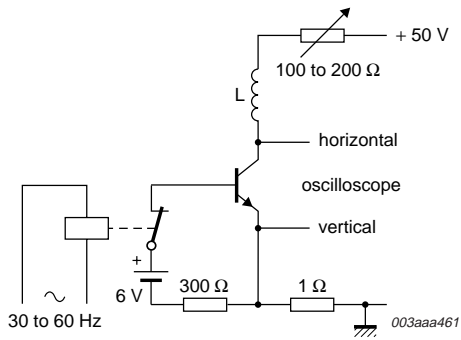


Fig 9. Test circuit for collector-emitter sustaining voltage.

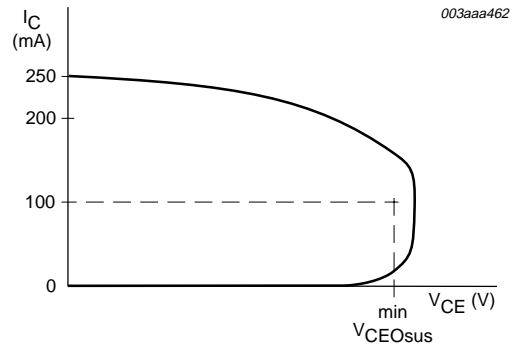
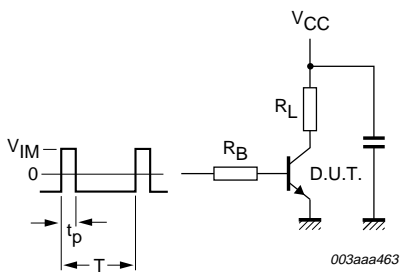


Fig 10. Oscilloscope display for collector-emitter sustaining voltage.



$V_{CC} = 250 \text{ V}$; $t_p = 20 \mu\text{s}$; $V_{IM} = -6 \text{ V to } 8 \text{ V}$; $t_p/T = 0.01$.
The values of R_B and R_L are selected in accordance with I_{Con} and I_{Bon} requirements.

Fig 11. Test circuit for resistive load switching times

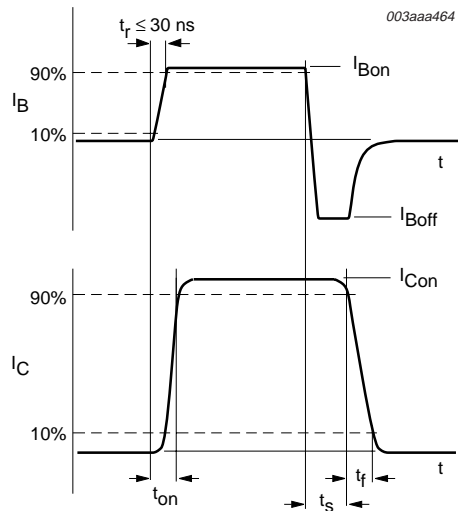
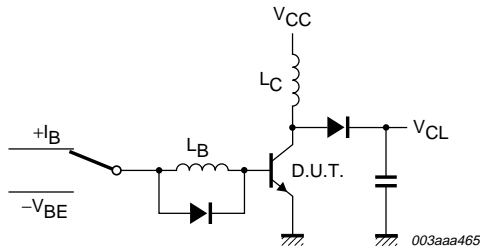


Fig 12. Switching time waveforms with resistive load.



$V_{CL} \leq 1000 \text{ V}$; $V_{CC} = 30 \text{ V}$; $V_{BE} = -1 \text{ V to } -5 \text{ V}$;
 $L_B = 1 \mu\text{H}$; $L_C = 200 \mu\text{H}$

Fig 13. Test circuit for inductive load switching and reverse bias safe operating area.

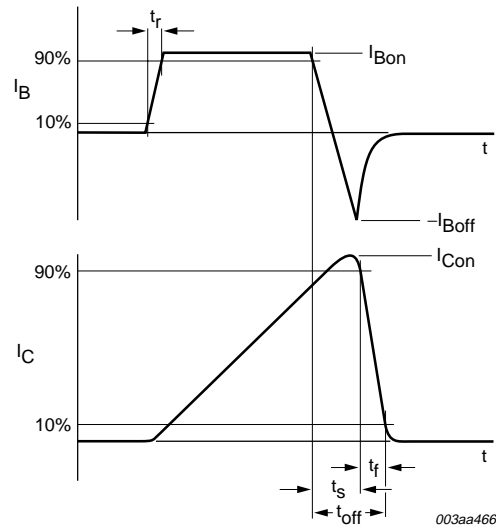


Fig 14. Switching time waveforms with inductive load.

7. Isolation characteristics

Table 6: Isolation characteristics

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|------------------|---|--|------|------|------|------|
| $V_{isol(RMS)M}$ | Peak RMS isolation voltage from all three terminals to external heatsink. | $f = 50 \text{ to } 60 \text{ Hz}$; sinusoidal waveform; $RH \leq 65\%$; clean and dust-free. | - | - | 2500 | V |
| C_{c-h} | Capacitance from collector to external heatsink. | | - | 12 | - | pF |

8. Package outline

Plastic single-ended package; isolated heatsink mounted;
1 mounting hole; 3 lead TO-220 'full pack'

SOT186A

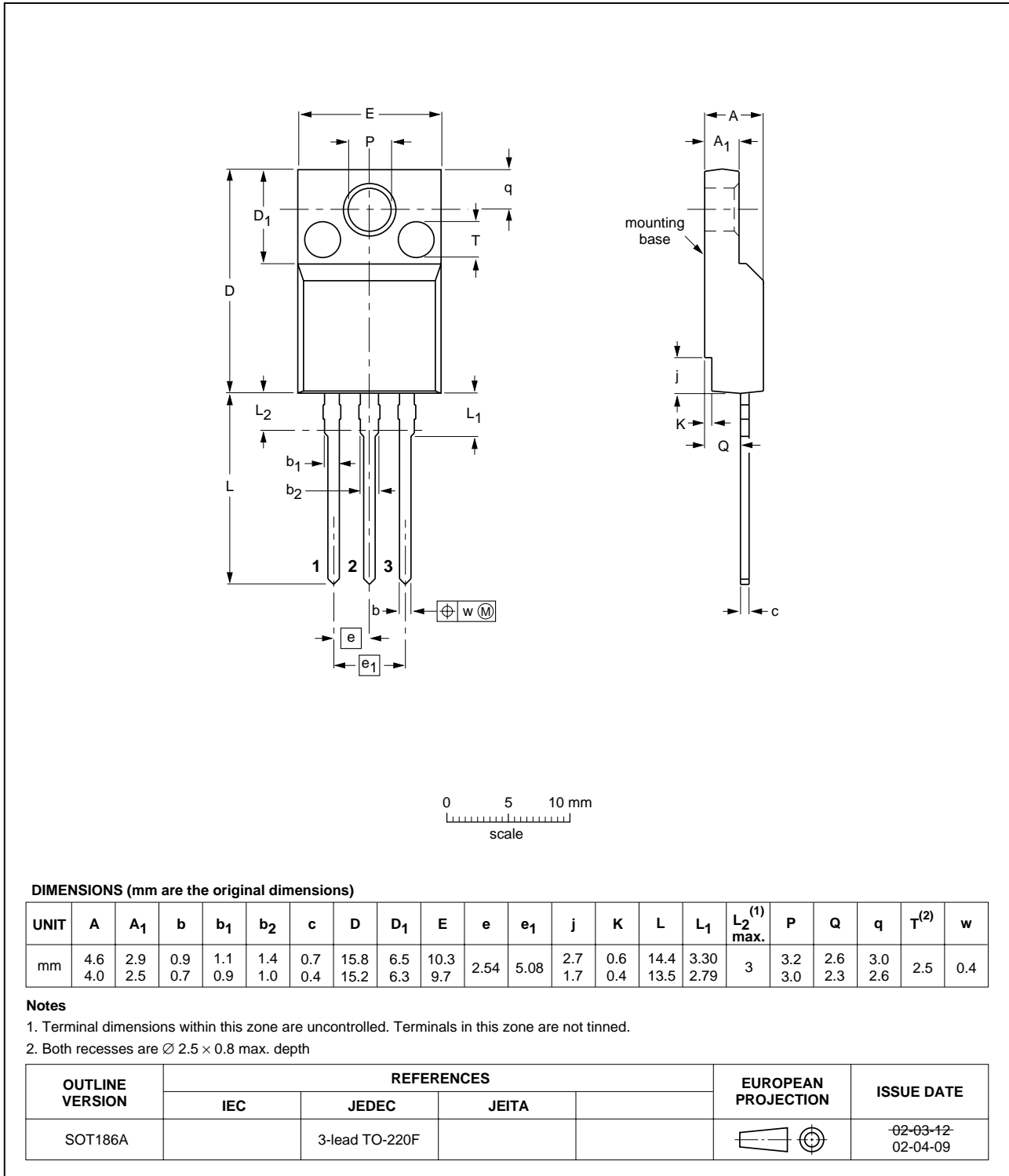


Fig 15. SOT186A (TO-220F).

9. Revision history

Table 7: Revision history

| Rev | Date | CPCN | Description |
|-----|----------|------|-------------------------------|
| 01 | 20040616 | - | Product data (9397 750 13442) |

10. Data sheet status

| Level | Data sheet status ^[1] | Product status ^{[2][3]} | Definition |
|-------|----------------------------------|----------------------------------|--|
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